

# NOT RECOMMENDED FOR NEW DESIGN USE DMP3125L



DMP3160L

#### P-CHANNEL ENHANCEMENT MODE MOSFET

# **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub>	I <sub>D</sub> T <sub>A</sub> = +25°C
001/	122mΩ @ V <sub>GS</sub> = -10V	-2.7A
-30V	190mΩ @ V <sub>GS</sub> = -4.5V	-2.0A

# **Description**

This new generation MOSFET is designed to minimize the on-state resistance ( $R_{DS(ON)}$ ) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

# **Applications**

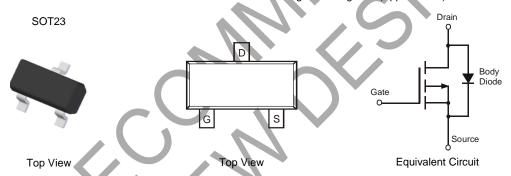
- DC-DC Converters
- Power Management Functions

### **Features**

- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

## **Mechanical Data**

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Terminal Connections: See Diagram
- Weight: 0.008 grams (Approximate)



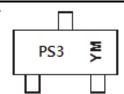
## Ordering Information (Note 5)

Part Number	Compliance	Case	Packaging
DMP3160L-7	Standard	SOT23	3000/Tape & Reel
DMP3160LQ-7	Automotive	SOT23	3000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to https://www.diodes.com/quality/product-compliance-definitions/.
- 5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

# **Marking Information**



PS3 = Product Type Marking Code YM = Date Code Marking Y or  $\overline{Y}$  = Year (ex: E = 2017) M = Month (ex: 9 = September)

Date Code Key

Year	2007		20	17	2018	2019	2020	2021	20	22	2023	2024
Code	U		- 1	Ξ	F	G	Ι	1	,	J	K	L
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

DMP3160L 1 of 6 November 2017

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**DMP3160L** 

# **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Character	istic		Symbol	Value	Unit
Drain-Source Voltage			V <sub>DSS</sub>	-30	V
Gate-Source Voltage			V <sub>GSS</sub>	±20	V
Drain Current (Note 6) $V_{GS} = -10V$ Steady $T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$		I <sub>D</sub>	-2.7 -2	А	
Pulsed Drain Current (Note 7)			I <sub>DM</sub>	-8	А

# **Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 6)	P <sub>D</sub>	1.08	W
Thermal Resistance, Junction to Ambient @T <sub>A</sub> = +25°C (Note 6)	$R_{ heta JA}$	115	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

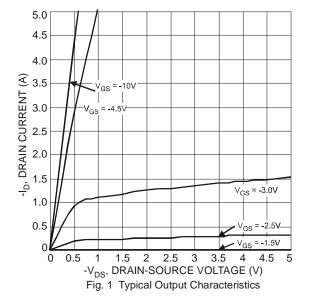
# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)			1			
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	-30		4	٧	$V_{GS} = 0V, I_D = -250\mu A$
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	1		-800	nA	$V_{DS} = -30V, V_{GS} = 0V$
Gate-Source Leakage	Igss			±80 ±800	nA	$V_{GS} = \pm 12V, V_{DS} = 0V$ $V_{GS} = \pm 15V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 8)						
Gate Threshold Voltage	V <sub>GS(TH)</sub>	-1.3	-1.8	-2.1	٧	$V_{DS} = V_{GS}, I_D = -250 \mu A$
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>		97	122	mΩ	$V_{GS} = -10V, I_D = -2.7A$
Static Drain-Source On-Nesistance	KDS(ON)		165	190	11122	$V_{GS} = -4.5V$ , $I_D = -2.0A$
Forward Transfer Admittance	Y <sub>fs</sub>	_ = 1	5.9		S	$V_{DS} = -5V, I_{D} = -2.7A$
Diode Forward Voltage (Note 8)	$V_{SD}$			-1.26	V	$V_{GS} = 0V$ , $I_S = -2.7A$
DYNAMIC CHARACTERISTICS(Note 9)						
Input Capacitance	Ciss	_	384.4		pF	., ,,,,,
Output Capacitance	Coss	_	59.4		pF	$V_{DS} = -10V, V_{GS} = 0V$ f = 1.0MHz
Reverse Transfer Capacitance	Crss	_	52.8		pF	1 - 1.01/11/2
Gate Resistance	R <sub>G</sub>	_	17.1	_	Ω	$V_{GS} = 0V$ , $V_{DS} = 0V$ , $f = 1.0MHz$
Total Gate Charge (V <sub>GS</sub> = -4.5V)	Qg	_	4.0	_	nC	
Total Gate Charge (V <sub>GS</sub> = -10V)	Qg	_	8.2	_	nC	$V_{GS} = -10V/-4.5V$ ,
Gate-Source Charge	Q <sub>gs</sub>	_	0.9		nC	$V_{DS} = -15V, I_{D} = -3A$
Gate-Drain Charge	Q <sub>gd</sub>	_	1.2	_	nC	
Turn-On Delay Time	t <sub>D(ON)</sub>	_	4.8	_	ns	
Turn-On Rise Time	t <sub>R</sub>	_	7.3		ns	$V_{DS} = -15V, V_{GS} = -10V,$
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	22.5		ns	$R_G = 6\Omega$ , $I_D = -1A$
Turn-Off Fall Time	t <sub>F</sub>	_	13.4	_	ns	

Notes:

- 6. Device mounted on FR-4 PCB.  $t \le 10$  sec.
- 7. Pulse width ≤10µS, Duty Cycle ≤1%.
  8. Short duration pulse test used to minimize self-heating effect.
  9. Guaranteed by design. Not subject to product testing.





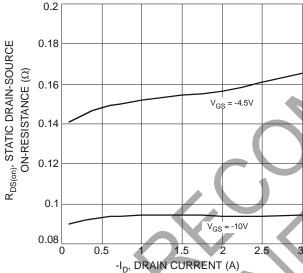


Fig. 3 On-Resistance vs. Drain Current and Gate Voltage

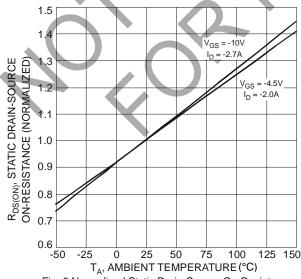
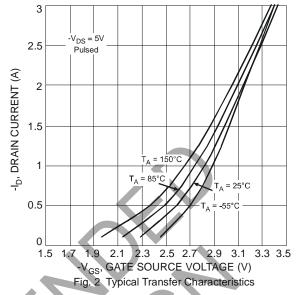


Fig. 5 Normalized Static Drain-Source On-Resistance vs. Ambient Temperature



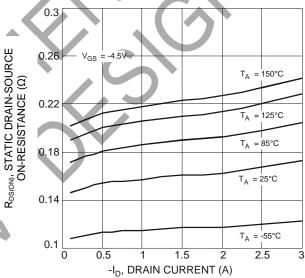
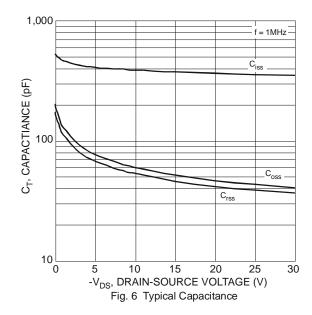
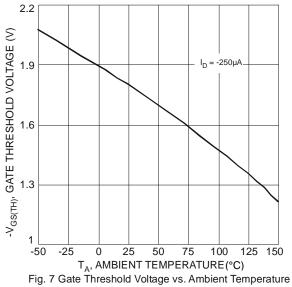
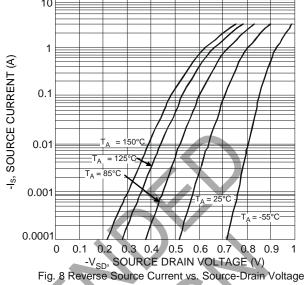


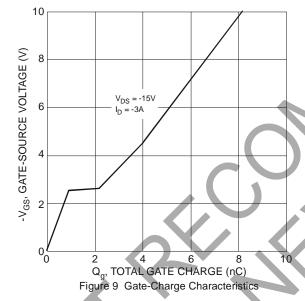
Fig. 4 On-Resistance vs. Drain Current and Gate Voltage









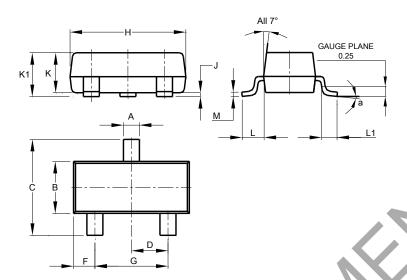




# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT23

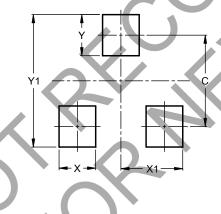


SOT23							
Dim	Min	Max	Тур				
Α	0.37	0.51	0.40				
В	1.20	1.40	1.30				
C	2.30	2.50	2.40				
D	0.89	1.03	0.915				
F	0.45	0.60	0.535				
G	1.78	2.05	1.83				
Н	2.80	3.00	2.90				
J	0.013	0.10	0.05				
K	0.890	1.00	0.975				
K1	0.903	1.10	1.025				
L	0.45	0.61	0.55				
L1	0.25	0.55	0.40				
M	0.085	0.150	0.110				
а	0°	8°					
All Dimensions in mm							

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### SOT23



Dimensions	Value (in mm)
С	2.0
X	0.8
X1	1.35
Y	0.9
Y1	2.9

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